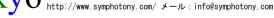


**BATOP** 



## SAM<sup>TM</sup> Data Sheet SAM-1064-50-5ps-x, $\lambda$ = 1064 nm

Laser wavelength  $\lambda = 1064 \text{ nm}$ 

High reflection band  $\lambda = 990 ... 1064 \text{ nm}$ 

Absorptance  $A_0 = 50 \%$  Modulation depth  $\Delta R = 25 \%$  Non-saturable loss  $A_{ns} = 25 \%$ 

Saturation fluence  $\Phi_{sat} = 21 \,\mu\text{J/cm}^2$ 

Relaxation time constant  $\tau \sim 5 \text{ ps}$ 

Damage threshold  $\Phi = 800 \,\mu\text{J/cm}^2$ 

Chip area 4.0 mm x 4.0 mm; other dimensions on request

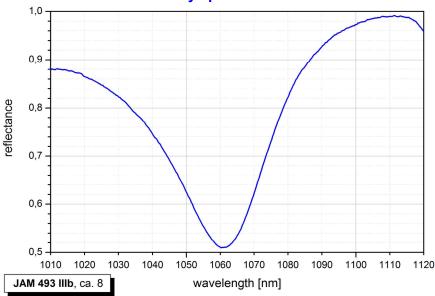
Chip thickness 450 µm

Protection the SAM is protected with a dielectric front layer

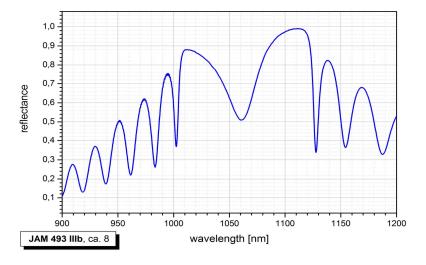
Mounting option  $\mathbf{x}$  denotes the type of mounting as follows:

x = 0
x = 12.7 g
x = 25.4 g
x = 12.7 s
x = 12.7 s
x = 12.7 s
x = 12.7 s
x = 25.4 s
x = 25.4 s
x = 25.4 s
x = 25.0 w
x

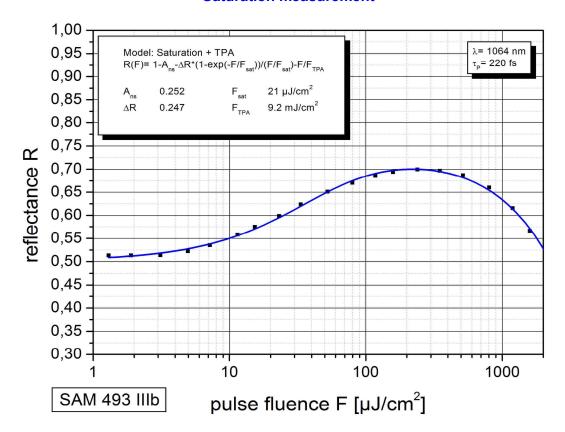
## Low intensity spectral reflectance







## **Saturation measurement**



## **Pump-probe measurement**



